

### NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE3008XM uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

#### **General Features**

•  $V_{DS} = 30V, I_{D} = 8A$ 

 $R_{DS(ON)} < 55 \text{m}\Omega$  @  $V_{GS}$ =2.5V

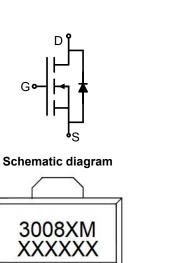
 $R_{DS(ON)}$  < 39m $\Omega$  @  $V_{GS}$ =4.5V

 $R_{DS(ON)}$  < 33m $\Omega$  @  $V_{GS}$ =10V

- High power and current handing capability
- Lead free product is acquired
- Surface mount package

### **Application**

- Battery switch
- ●DC/DC converter



SOT-89 -3L top view

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3008XM	NCE3008XM	SOT-89-3L	Ø180mm	12mm	1000units

### Absolute Maximum Ratings (T<sub>A</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	30	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	I <sub>D</sub>	8	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	30	Α
Maximum Power Dissipation	P <sub>D</sub>	3.5	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	°C

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	35	°C/W

### **Electrical Characteristics (T<sub>A</sub>=25**°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	30		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V	-	-	1	μA



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# NCE3008XM

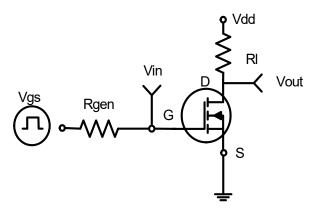
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	0.7	0.9	1.4	V
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =4A	-	33	55	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A	-	26	39	mΩ
		V <sub>GS</sub> =10V, I <sub>D</sub> =8A	-	24	33	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =8A	10	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ -45\/\/ -0\/	-	595	-	PF
Output Capacitance	Coss	$V_{DS}$ =15V, $V_{GS}$ =0V, F=1.0MHz	-	39	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0IVITZ	-	36	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	3.0	-	nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =15V, R <sub>L</sub> =1.8Ω	-	4.5	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{GEN}$ =3 $\Omega$	-	25	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	3.8	-	nS
Total Gate Charge	Qg	\/ -45\/1-04	-	9.3	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=15V, I_{D}=8A,$ $V_{GS}=4.5V$	-	1.6	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> -4.5V	-	2.1	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =8A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	8	Α
			•			

### Notes:

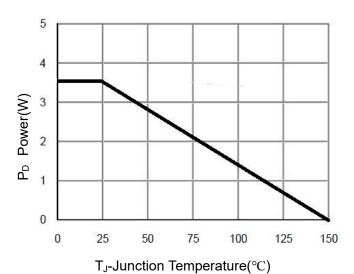
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



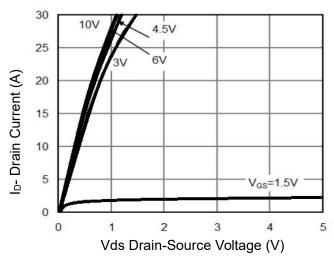
## **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 



**Figure 5 Output Characteristics** 

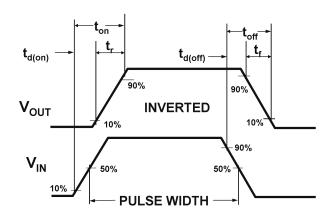
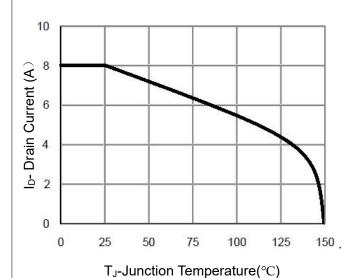


Figure 2:Switching Waveforms



**Figure 4 Drain Current** 

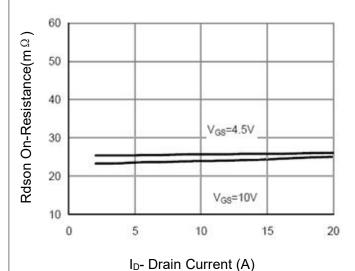
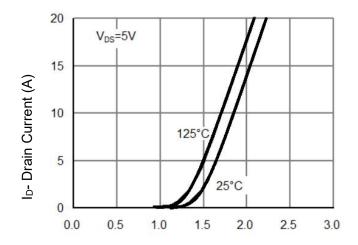
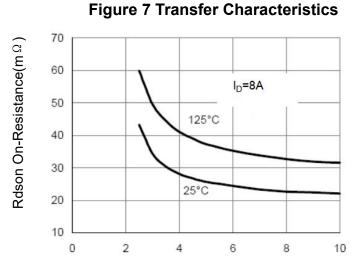


Figure 6 Drain-Source On-Resistance





Vgs Gate-Source Voltage (V)



Vgs Gate-Source Voltage (V)

Figure 9 Rdson vs Vgs

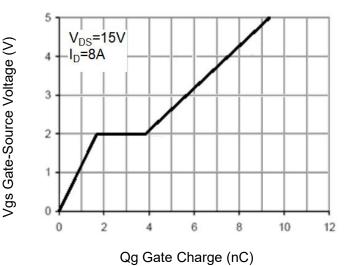
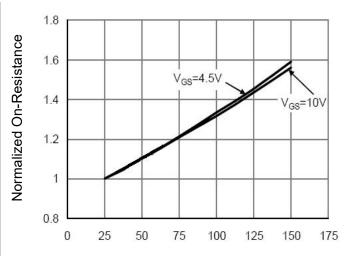


Figure 11 Gate Charge



T<sub>J</sub>-Junction Temperature(°C)

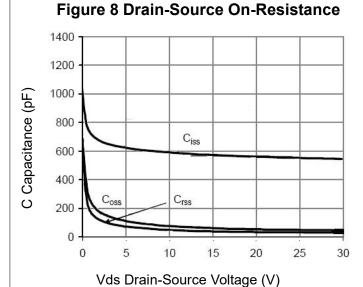


Figure 10 Capacitance vs Vds

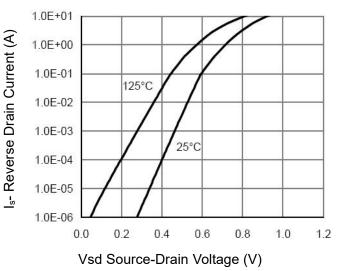
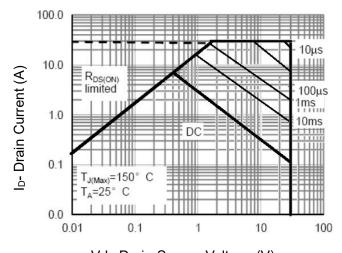


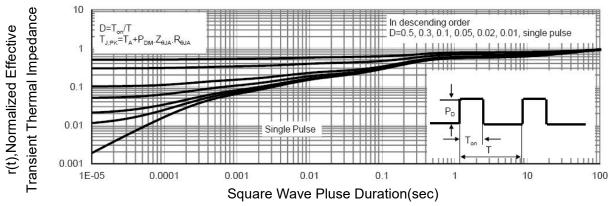
Figure 12 Source- Drain Diode Forward





Vds Drain-Source Voltage (V)

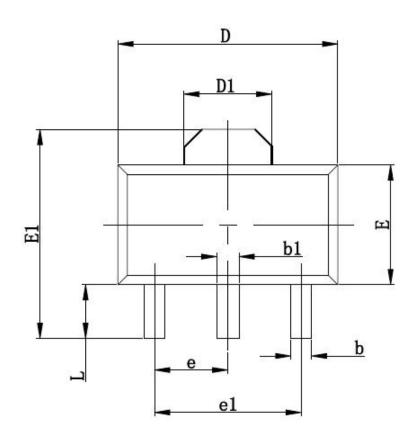
**Figure 13 Safe Operation Area** 

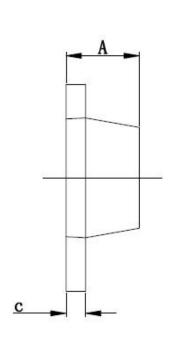


**Figure 14 Normalized Maximum Transient Thermal Impedanc** 



## **SOT-89-3L Package Information**





Cumple of	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.400	1.600	0.055	0.063	
b	0.350	0.520	0.013	0.197	
b1	0.400	0.580	0.016	0.023	
С	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550	REF	0.061 REF		
E	2.350	2.550	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
е	1.500 TYP		0.06	OTYP	
e1	3.000 TYP		0.11	8TYP	
L	0.900	1.100	0.035	0.047	



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# NCE3008XM

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STF5N65M6 IRF40H233XTMA1 STU5N65M6 DMN6022SSD-13 DMN13M9UCA6-7 DMTH10H4M6SPS-13 IPS60R360PFD7SAKMA1
DMN2990UFB-7B SSM3K35CT,L3F IPLK60R1K0PFD7ATMA1 2N7002W-G MCAC30N06Y-TP IPWS65R035CFD7AXKSA1
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